Vishay Semiconductors



Hyperfast Rectifier, 2 x 10 A FRED Pt®



Common cathode Anode Anode

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 10 A					
V _R	300 V					
V _F at I _F	0.85 V					
t _{rr} typ.	See Recovery table					
T _J max.	175 °C					
Package	TO-220 FullPAK 3L					
Circuit configuration	Common cathode					

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage		V _{RRM}		300	V	
Average restified forward ourrest	per diode	1	T _C = 135 °C	10		
Average rectified forward current per dev		IF(AV)		20	А	
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C	120		
Operating junction and storage temperat	ures	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	300	-	-		
	V	I _F = 10 A		1.05	1.25	V	
Forward voltage V _F		I _F = 10 A, T _J = 125 °C	-	0.85	0.95		
Deverse leekege eurrent		$V_{R} = V_{R}$ rated	-	-	20		
Reverse leakage current I _R		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	6	200	μA	
Junction capacitance	CT	V _R = 300 V	-	30	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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RoHS COMPLIANT

HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1 A, dI _F /dt = 50 A	õs, V _R = 30 V	-	-	35		
Reverse recovery time	+	I _F = 1 A, dI _F /dt = 100 A/μs, V _R = 30 V		-	-	30		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	31	-	ns	
		T _J = 125 °C	l _F = 10 A dl _F /dt = 200 A/µs	-	42	-		
Peak recovery current I _{RRM}	1	T _J = 25 °C		-	2.4	-		
	IRRM	T _J = 125 °C	$V_{\rm R} = 200 \text{ V}$	-	5.6	-	A	
Reverse recovery charge	0	T _J = 25 °C		-	36	-	nC	
	Q _{rr}	T _J = 125 °C		-	120	-	no	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction-to-case per diode	R _{thJC}	Mounting surface, flat, smooth, and greased	-	-	3.9	°C/W	
Marking device		Case style TO-220 FullPAK 3L		20CTI	H03FP		

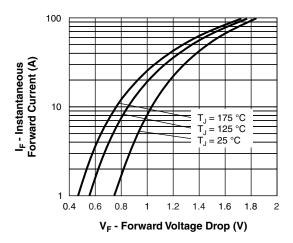


Fig. 1 - Typical Forward Voltage Drop Characteristics

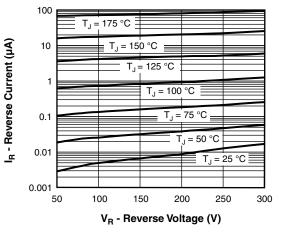
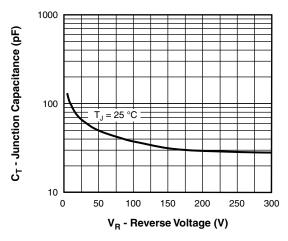
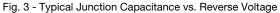


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





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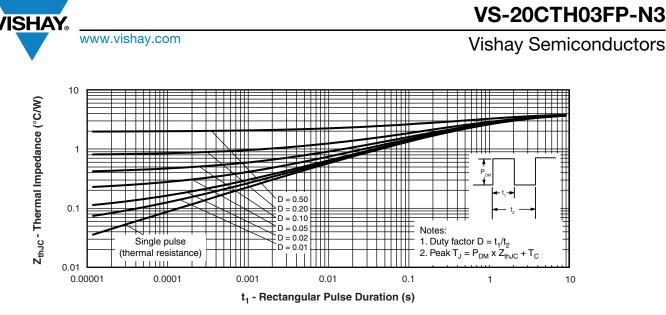


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

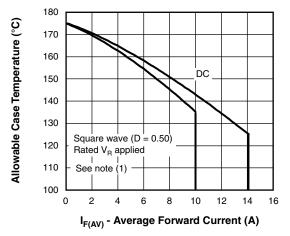
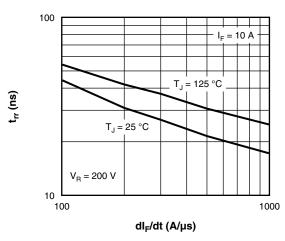


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

Note





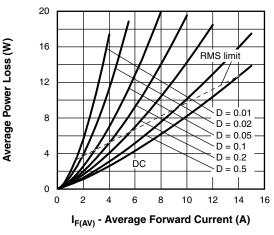


Fig. 6 - Forward Power Loss Characteristics

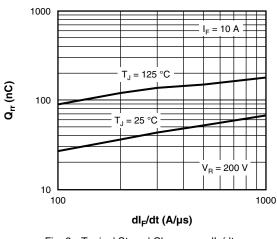


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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VS-20CTH03FP-N3

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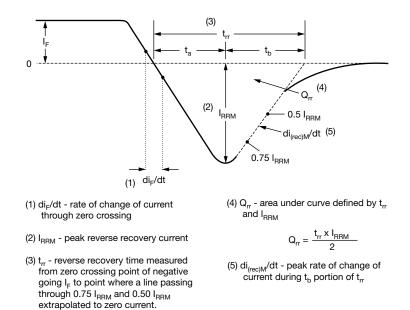


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

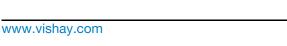
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Device code	vs-	20	С	т	н	03	FP	-N3
		2	3	4	5	6	7	8
	1 2 3	- C	shay Serr urrent rati = commo	ng (20 =	: 20 A)	oduct		
	4	- т	= TO-220 = hyperfa	, D ² PAk	K (TO-26	63AB)		
	6 7		oltage rati P = TO-22	0.	,			
	8		nvironmer 13 = halog	•		complia	ant, and	l totally

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20CTH03FP-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96155				
Part marking information	www.vishay.com/doc?95456				
SPICE model	www.vishay.com/doc?96584				

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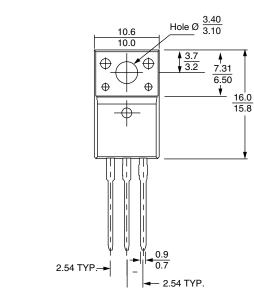


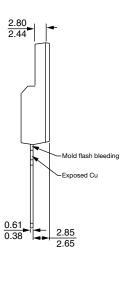
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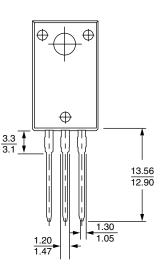
3L TO-220 FullPAK

DIMENSIONS in millimeters

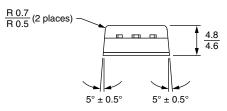
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Bottom view



Notes

- ⁽¹⁾ All dimensions are in mm
- ⁽²⁾ Package body size exclude mold flash and burrs. Moldflash should be less than 6 mils



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